


SANYO Semiconductors

DATA SHEET

LA0225CV — PN type Photo Diode For Optical Disk Blue-purple Laser Diode monitor

Overview

LA0225CV is a photo diode for optical disk blue-purple laser diode monitor.

Functions

- The blue-purple sensitive PN type photo diode
- Photo diode opening size: 1.0mm□
- High sensitivity and light stability by the AR coating cover glass adoption.
- Small size and thin type CSP Package: ODCSP4J, size: 1.22mm×1.38mm×0.58mm
- Pb free, capable of reflow mounting

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Reverse voltage	V _R		10	V
Operating temperature	T _{opr}		-30 to +85	°C
Storage temperature	T _{stg}		-40 to +85	°C

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LA0225CV

Electrical and Optical Characteristics at Ta = 25°C, VCC = 5V

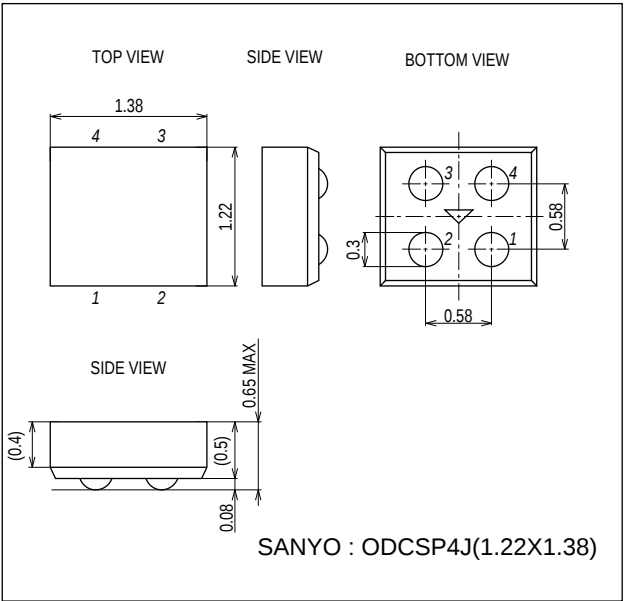
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Dark current	I_D	$V_R = 10V$		0.01	2	nA
Receiving sensitivity *	GB	$\lambda = 405nm$	0.22	0.28		A/W
	GD	$\lambda = 650nm$	0.34	0.44		A/W
	GC	$\lambda = 780nm$	0.33	0.43		A/W
Forward voltage	V_F	$I_F = 0.1mA$	410	510	610	mV
Inter-terminal capacitance *	C	$V_R = 2.5V$		65		pF

* Design reference value (indication of deviation), the characteristic is not guaranteed.

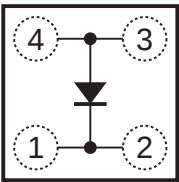
Package Dimensions

unit: mm (typ)

3367



Block Diagram

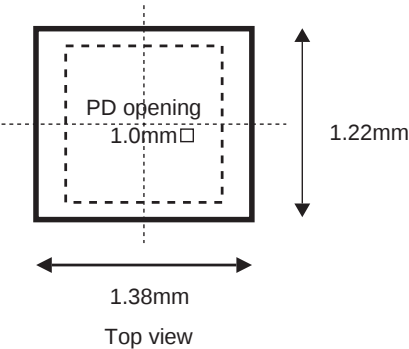


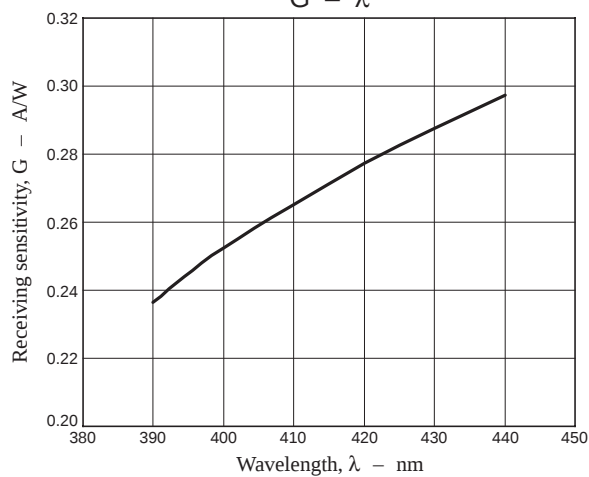
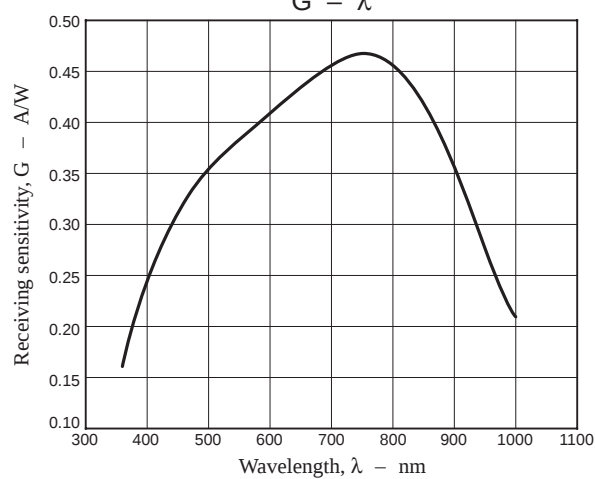
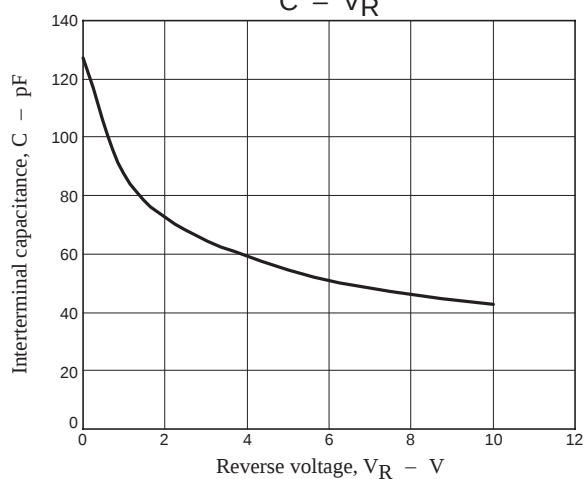
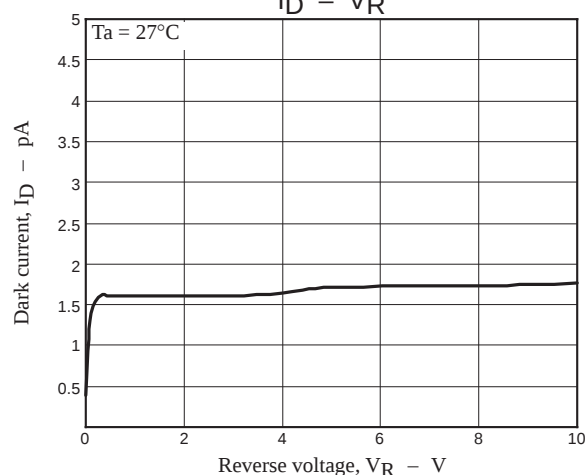
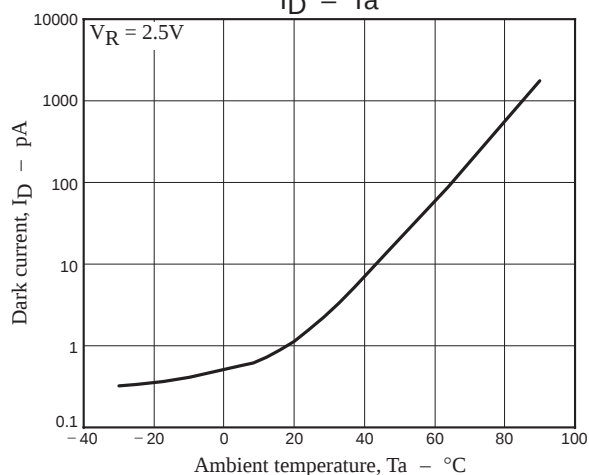
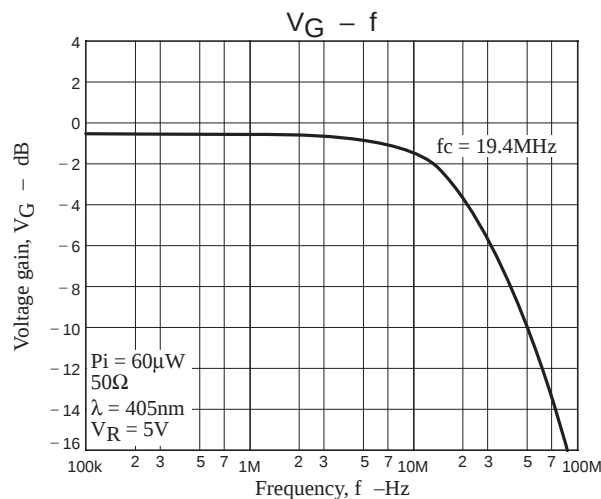
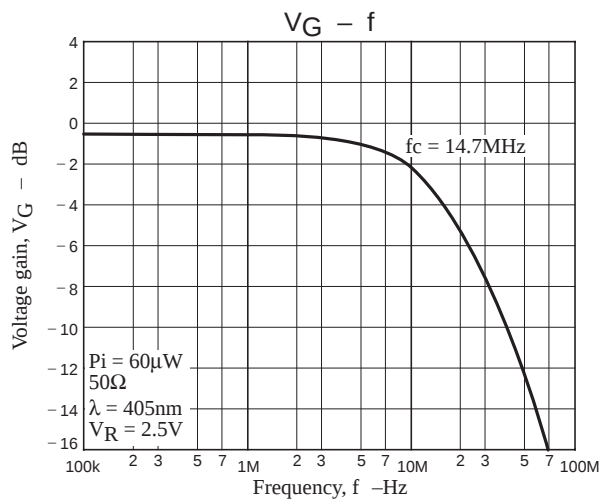
Top view

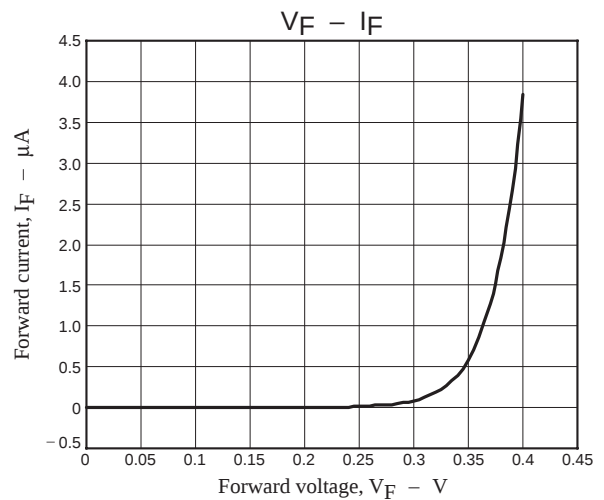
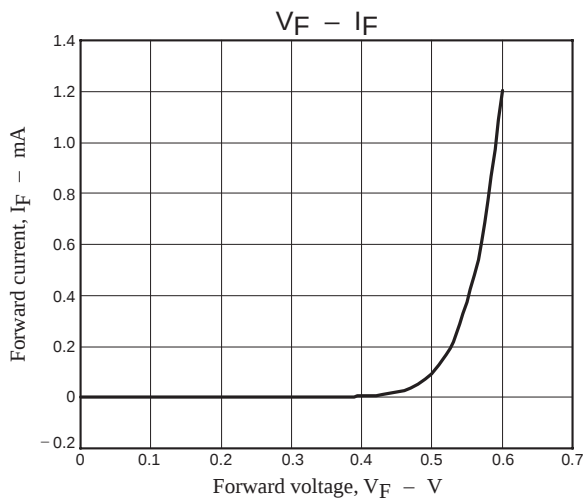
Pin No.	Pin name	Function
1,2	cathode	cathode pin
3,4	anode	anode pin

Receiving Layout

Package center and photo diode opening center is same.







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